

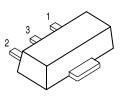


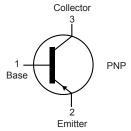
Features:

- For AF driver and output stages
- · High collector current
- · Low collector-emitter saturation voltage
- Complementary types: BCX54/BCX55/BCX56

Applications:

- Medium power general purposes
- · Driver stages of audio amplifiers





Pin Configuration:

- 1. Base
- 2. Emitter
- 3. Collector

Maximum Ratings

Parameter	Symbol	Value	Unit	
Collector - Base Voltage - BCX51 - BCX52 - BCX53	V _{CBO}	-45 -60 -100		
Collector - Emitter Voltage - BCX51 - BCX52 - BCX53	V _{CEO}	-45 -60 -80	V	
Emitter - Base Voltage	$V_{\rm ebo}$	-5		
Collector Current - Continuous	I _C	-1		
Collector Current - Peak	I _{CM}	-1.5	А	
Total device Dissipation	P _D	500	mW	
Junction and Storage Temperature	T _j , T _{stg}	-65 to +150	°C	

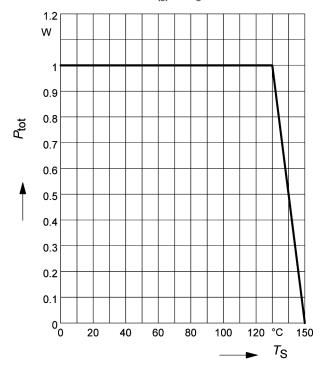




Electrical Characteristics ($T_a = 25$ °C unless otherwise noted)

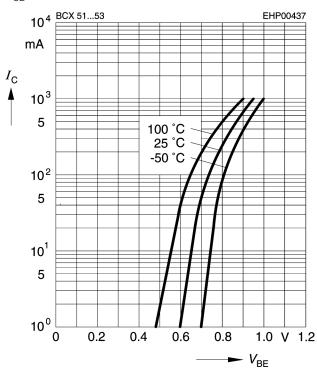
Parameter	Symbol	Test Conditions	Min.	Тур.	Max.	Unit
Collector - Base Breakdown Voltage	V _{(BR)CBO}	I _C =-100μA, I _E =0 BCX51 BCX52 BCX53	-45 -60 -100			
Collector - Emitter Breakdown Voltage	V _{(BR)CEO}	I _C =-10mA, I _B =0 BCX51 BCX52 BCX53	-45 -60 -80			V
Emmiter - Base Breakdown Voltage	V _{(BR)EBO}	I _E =-10μA, I _C =0	-5			
Collector Cut-Off Current	I _{CBO}	V _{CB} =-30V, I _E =0			-0.1	Α
DC Current Gain	h _{FE}	V _{CE} =-2V, I _C =-5mA V _{CE} =-2V, I _C =-150mA V _{CE} =-2V, I _C =-150mA -10 -16 V _{CE} =-2V, I _C =-500mA	25 40 63 100 25		250 160 250	
Collector - Emitter Saturation Voltage	V _{CE(sat)}	I _C =-500mA, I _B =-50mA			-0.5	V
Base Emitter Voltage	V _{BE}	I _C =-500mA, V _{CE} =-2V			-1	V
Transition Frequency	f _T	V _{CE} =-10, I _C =-50, f=20MH		125		MHz

Total power dissipation $P_{\text{tot}} = f(T_{S})$



Collector current $I_{\rm C}$ = $f(V_{\rm BE})$

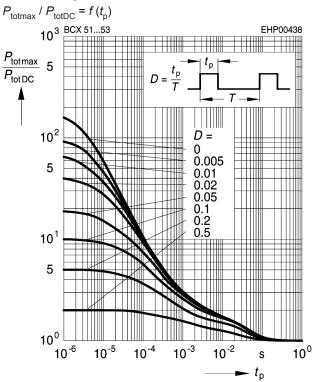
$$V_{CE} = 2V$$



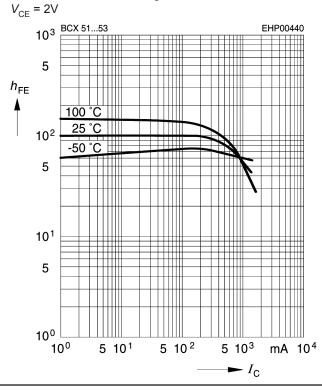




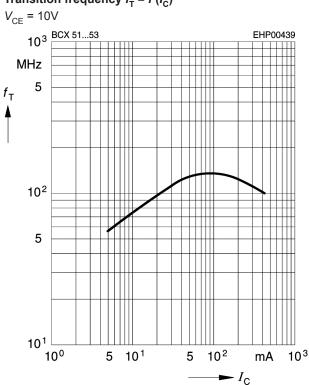
Permissible pulse load



DC current gain $hFE = f(I_C)$

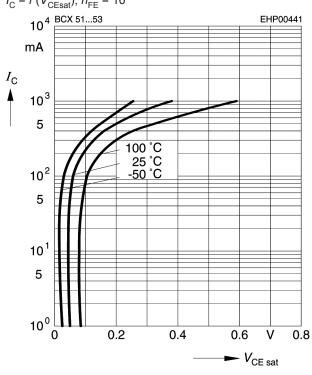


Transition frequency $f_T = f(I_C)$



Collector-emitter saturation voltage

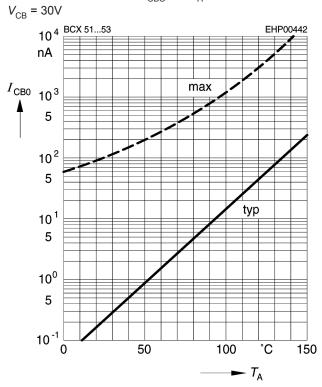
$$I_{\rm C} = f(V_{\rm CEsat}), h_{\rm FE} = 10$$





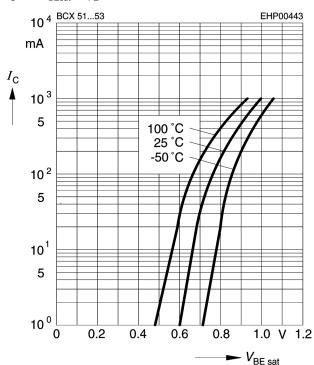


Collector cutoff current $I_{CBO} = f(T_A)$



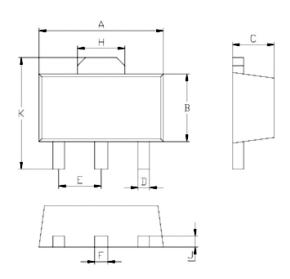
Base-emitter saturation voltage

$$I_{\rm C} = f(V_{\rm BEsat}), h_{\rm FE} = 10$$



Package Outline

Plastic surface mounted package

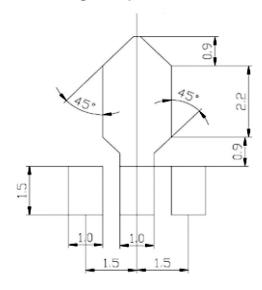


Dimensions	Min.	Max.	
А	4.5	4.7	
В	2.3	2.7	
С	1.5 Typical		
D	0.35	0.55	
E	1.4	1.6	
F	0.4	0.6	
Н	1.55	1.75	
J	0.4 Typical		
K	4.15	4.25	

Dimensions : Millimetres



Soldering Footprint



Dimensions: Millimetres

Part Number Table

Description	Part Number
Transistor, PNP, 1A, 45V, SOT-89	BCX51
Transistor, PNP, 1A, 45V, SOT-89	BCX51-16
Transistor, PNP, 1A, 60V, SOT-89	BCX52-16
Transistor, PNP, 1A, 80V, SOT-89	BCX53-10
Transistor, PNP, 1A, 80V, SOT-89	BCX53-16

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